## NSN 5961-01-359-3125

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-359-3125
Inclosure Material:
Metal
Overall Length:
Between 0.975 inches and 1.130 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Mounting Method:
Threaded stud
Overall Width Across Flats:
Between 0.424 inches and 0.437 inches
Thread Size:
0.190 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage
static, collector open
Current Rating Per Characteristic:
5.00 amperes source cutoff current and 500.00 milliamperes source cutoff current
Power Rating Per Characteristic:
30.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Thread Series Designator:
Unf
Terminal Type And Quantity:
3 wire hook
Specification Data:
81349-mil-s-19500/374 government specification
Shelf Life:
N/a
Unit Of Measure:
<del></del>
Demilitarization:

Fiig:

Yes - demil/mli